NSN 5962-01-355-3767

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View Online at https://aerobasegroup.com/nsn/5962-01-355-3767

Body Length: 0.640 inches **Body Width:** Between 0.300 inches and 0.420 inches **Body Height:** Between 0.045 inches and 0.090 inches **Maximum Power Dissipation Rating:** 1.2 watts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Hermetically sealed and burn in and monolithic and positive outputs **Inclosure Material:** Ceramic **Inclosure Configuration:** Flat pack **Output Logic Form:** Complementary-metal oxide-semiconductor logic **Input Circuit Pattern:** 22 input **Case Outline Source And Designator:** F-6 mil-m-38510 **Current Rating Per Characteristic:** 100.00 milliamperes reverse current, dc absolute **Terminal Surface Treatment:** Solder **Product Name:** And-or-logic array Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Capitance Rating Per Characteristic:** 10.00 input picofarads and 10.00 output picofarads **Time Rating Per Chacteristic:** 25.00 nanoseconds access Memory Device Type: Pal **Test Data Document:** 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

Terminal Type And Quantity:

24 flat leads

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Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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